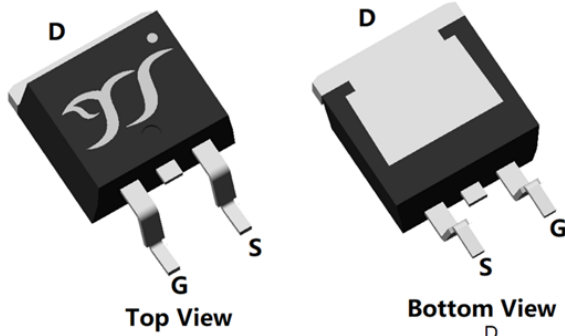
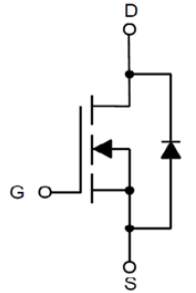


N-Channel Enhancement Mode Field Effect Transistor



TO-263



Product Summary

- V_{DS} 100V
- I_D 70A
- $R_{DS(ON)}$ (at $V_{GS}=10V$) <8.6 mohm
- $R_{DS(ON)}$ (at $V_{GS}=6V$) <13 mohm
- 100% EAS Tested
- 100% ∇V_{DS} Tested

General Description

- Low $R_{DS(on)}$ & FOM
- Extremely low switching loss
- Excellent stability and uniformity
- Fast switching and soft recovery
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- Power switching application
- Hard switched and high frequency circuits
- UPS

■ Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-source Voltage		V_{DS}	100	V
Gate-source Voltage		V_{GS}	± 20	V
Drain Current ^A (Package Limited)	$T_A=25^\circ C$	I_D	10	A
	$T_A=100^\circ C$		6	
	$T_C=25^\circ C$		70	
	$T_C=100^\circ C$		44	
Pulsed Drain Current ^B		I_{DM}	280	A
Avalanche energy ^C		EAS	200	mJ
Total Power Dissipation ^D	$T_A=25^\circ C$	P_D	2	W
	$T_A=100^\circ C$		0.8	
	$T_C=25^\circ C$		125	
	$T_C=100^\circ C$		50	
Junction and Storage Temperature Range		T_J, T_{STG}	-55~+150	$^\circ C$

■ Thermal resistance

		Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient ^E	$t \leq 10S$	$R_{\theta JA}$	12	15	$^\circ C/W$
Thermal Resistance Junction-to-Ambient ^E	Steady-State		50	60	
Thermal Resistance Junction-to-Case	Steady-State	$R_{\theta JC}$	0.8	1.0	

■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJB70G10B	F2	YJB70G10B	800	/	8000	13" reel



YJB70G10B

■ Electrical Characteristics (T_J=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} = 0V, I _D =250μA	100			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V, V _{GS} =0V			1	μA
		V _{DS} =100V, V _{GS} =0V, T _J =150°C			100	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} = ±20V, V _{DS} =0V			±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D =250μA	2	2.8	4	V
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} = 10V, I _D =20A		7.2	8.6	mΩ
		V _{GS} = 6V, I _D =20A		10	13	mΩ
Diode Forward Voltage	V _{SD}	I _S =20A, V _{GS} =0V			1.3	V
Maximum Body-Diode Continuous Current	I _S				70	A
Gate resistance	R _G	f= 1 MHz		0.68		Ω
Dynamic Parameters						
Input Capacitance	C _{iss}	V _{DS} =50V, V _{GS} =0V, f=1MHZ		2270		pF
Output Capacitance	C _{oss}			797		
Reverse Transfer Capacitance	C _{rss}			36		
Switching Parameters						
Total Gate Charge	Q _g	V _{GS} =10V, V _{DS} =50V, I _D =25A		32		nC
Gate-Source Charge	Q _{gs}			11.1		
Gate-Drain Charge	Q _{gd}			4.78		
Reverse Recovery Chrage	Q _{rr}	I _F =20A, di/dt=100A/us		84		ns
Reverse Recovery Time	t _{rr}			51.5		
Turn-on Delay Time	t _{D(on)}	V _{GS} =10V, V _{DD} =50V, I _D =25A R _{GEN} =2.2Ω		51		ns
Turn-on Rise Time	t _r			14.4		
Turn-off Delay Time	t _{D(off)}			69.2		
Turn-off fall Time	t _f			20.6		

- A. The maximum current rating is package limited.
 B. Repetitive rating; pulse width limited by max. junction temperature.
 C. V_{DD}=50V, R_G=25Ω, L=0.5mH, starting T_J=25 °C.
 D. Pd is based on max. junction temperature, using junction-case thermal resistance.
 E. The value of R_{θJA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C. The Power dissipation PDSM is based on R_{θJA} ≤ 10s and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.



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■ Typical Performance Characteristics

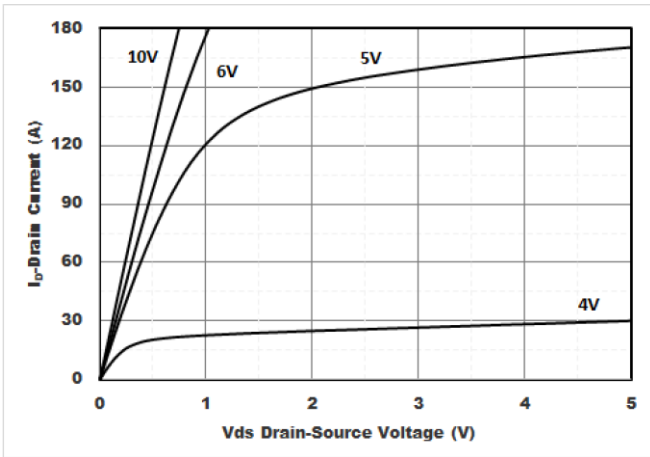


Figure1. Output Characteristics

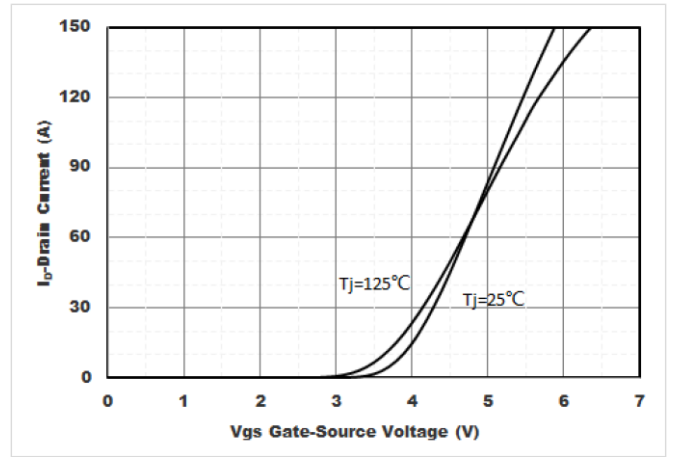


Figure2. Transfer Characteristics

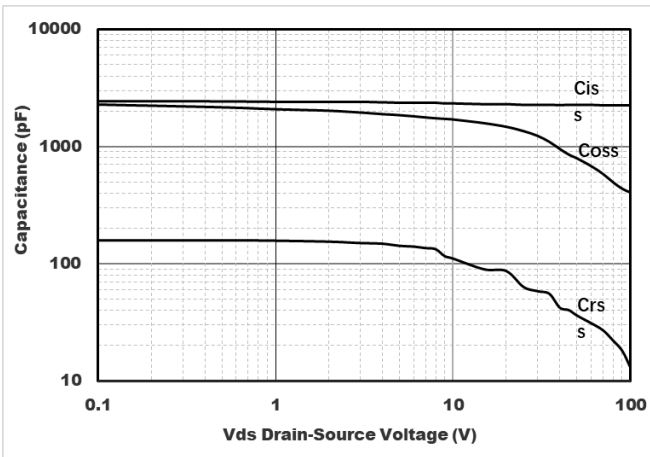


Figure3. Capacitance Characteristics

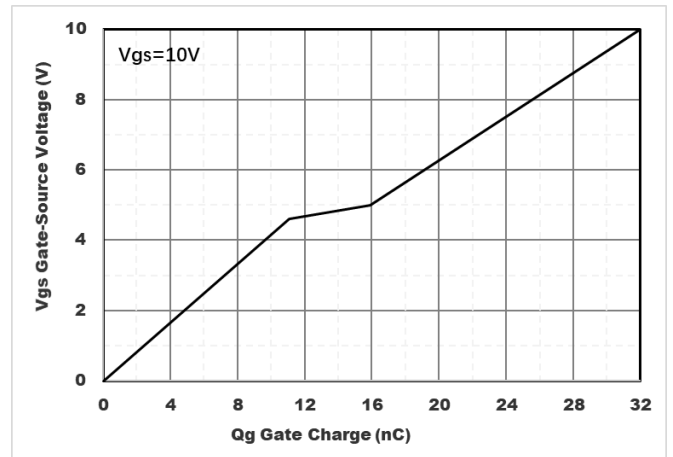


Figure4. Gate Charge

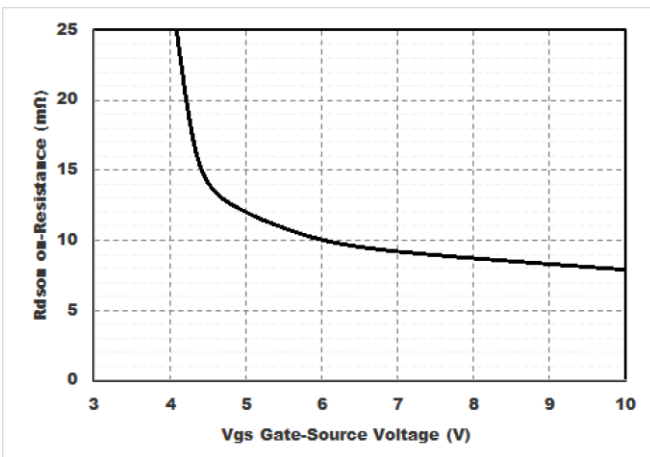


Figure5. : On-Resistance vs. Drain Current and Gate Voltage

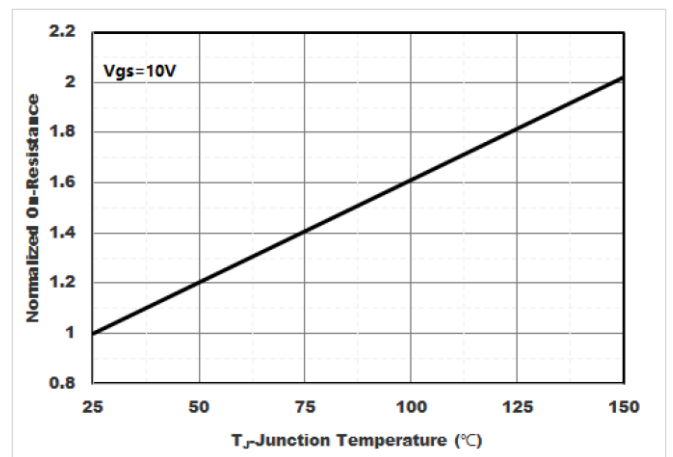


Figure6. Normalized On-Resistance



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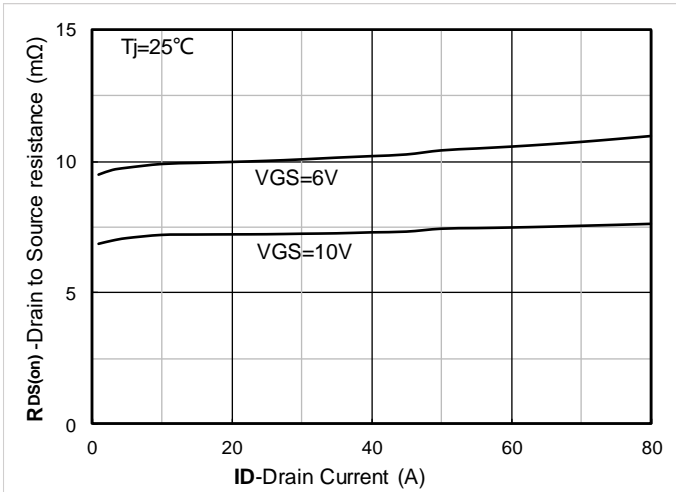


Figure 7. $R_{DS(on)}$ VS Drain Current

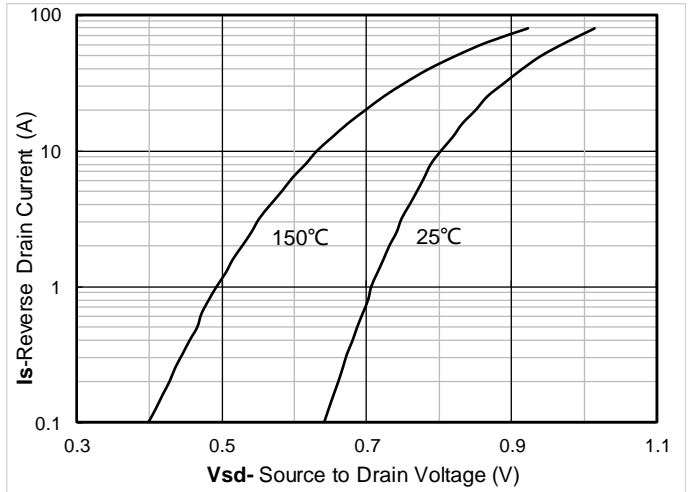


Figure 8. Forward characteristics of reverse diode

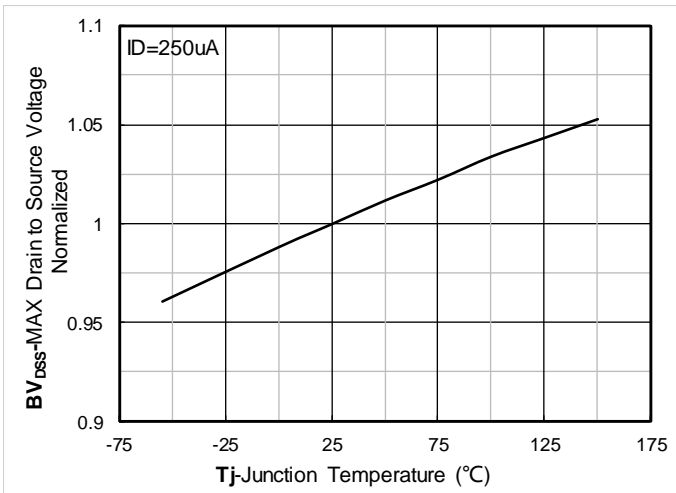


Figure 9. Normalized breakdown voltage

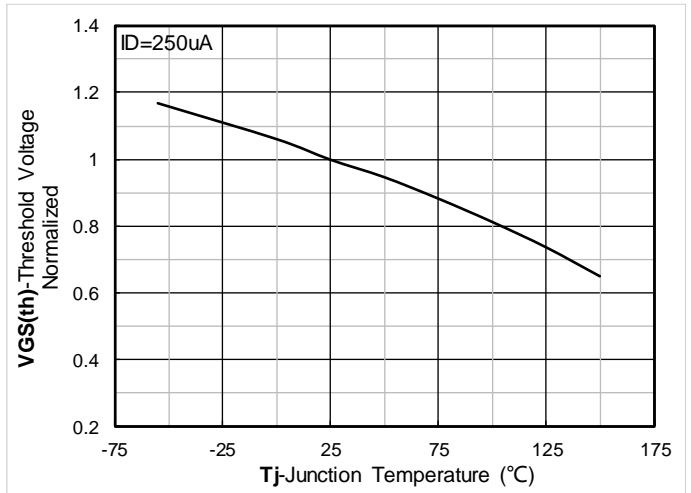


Figure 10. Normalized Threshold voltage

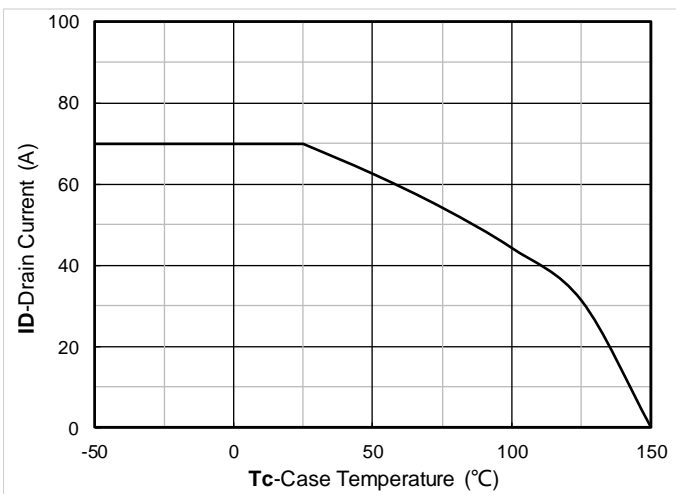


Figure 11. Current dissipation

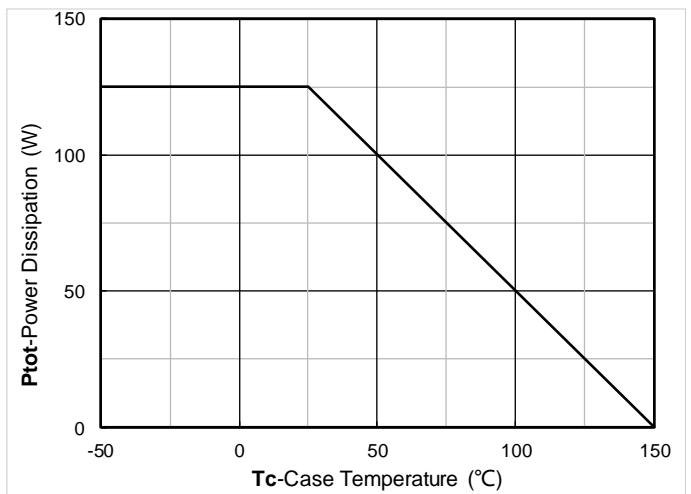


Figure 12. Power dissipation



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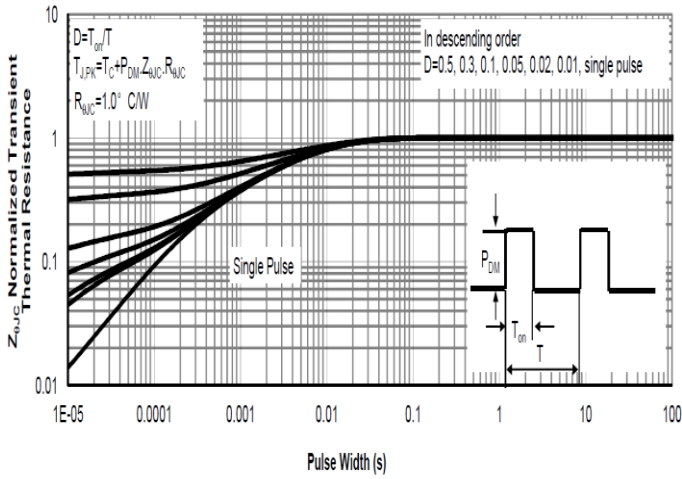


Figure 13. Normalized Maximum Transient thermal impedance

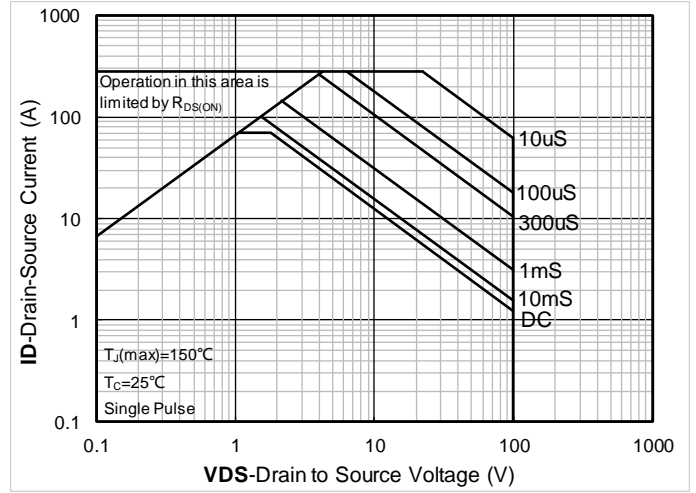
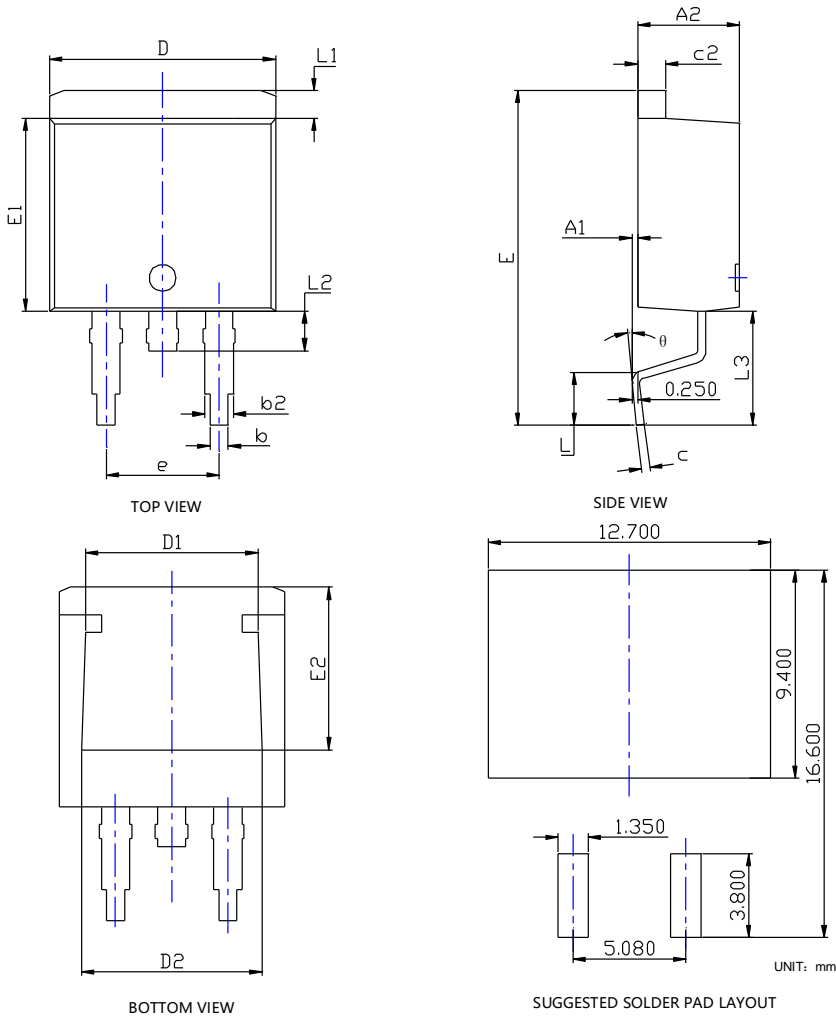


Figure 14. Safe Operation Area



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■ TO-263-HY Package information



SYMBOL	DIMENSIONS					
	INCHES			Millimeter		
	MIN.	NDM.	MAX.	MIN.	NDM.	MAX.
A1	0.000	---	0.010	0.000	---	0.250
A2	0.174	0.180	0.186	4.430	4.580	4.730
b	0.028	0.032	0.036	0.720	0.820	0.920
b2	0.046	0.050	0.054	1.180	1.280	1.380
c	0.013	0.015	0.018	0.330	0.390	0.450
c2	0.048	0.050	0.053	1.220	1.280	1.340
D	0.394	0.400	0.406	10.000	10.150	10.300
D1	0.295	0.307	0.319	7.500	7.800	8.100
D2	0.303	0.315	0.327	7.700	8.000	8.300
E	0.571	0.591	0.610	14.500	15.000	15.500
E1	0.337	0.341	0.348	8.550	8.700	8.850
E2	0.276	0.287	0.299	7.000	7.300	7.600
e	0.200BSC			5.080BSC		
L	0.070	---	0.110	1.790	---	2.790
L1	0.044	---	0.056	1.120	---	1.420
L2	0.030	---	0.070	0.770	---	1.770
L3	0.197REF			5.000REF		
θ	0°	---	8°	0°	---	8°

NOTE:
 1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
 2. TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
 3. THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.



YJB70G10B

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